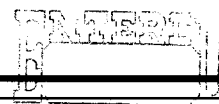
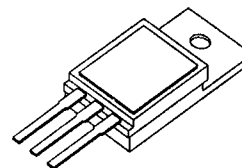




PRELIMINARY

SOLID STATE DEVICES, INC14849 Firestone Boulevard · La Mirada, CA 90638
Phone: (714) 670-SSDI (7734) · Fax: (714) 522-7424**SSR2010CTC****Designer's Data Sheet****FEATURES:**

- PIV: 100 Volts
- Low Reverse Leakage
- Low Forward Voltage Drop
- Guard Ring for Overvoltage protection
- Isolated Hermetically Sealed Power Package
- Low inductance leads
- Ideal for High Voltage Applications
- Custom Lead Forming Available
- Eutectic Die Attach
- 175°C Operating Temperature
- TX, TXV and Space Level Screening Available

**20 AMP
100 VOLTS
POSITIVE CENTERTAP
SCHOTTKY
RECTIFIER****CERAMIC TO-254C****MAXIMUM RATINGS**

RATING	SYMBOL	VALUE	UNIT
Peak Repetitive Reverse and DC Blocking Voltage	VRRM	100	Volts
	VRWM		
	VR		
Average Rectified Forward Current (Resistive Load, 60Hz, Sine Wave, TA=25°C)	IO	20	Amps
Peak Surge Current (8.3 ms Pulse, Half Sine Wave Superimposed on IO, allow junction to reach equilibrium between pulses, TA=25°C)	IFSM	200	Amps
Operating and storage temperature	Top & Tstg	-65 to +175	°C
Maximum Thermal Resistance Junction to Case, both legs tied together	RθJC	1.0	°C/W

NOTE: All specifications are subject to change without notification.
SCD's for these devices should be reviewed by SSDI prior to release.**DATA SHEET #: RS0079 B****MED**

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SSDI

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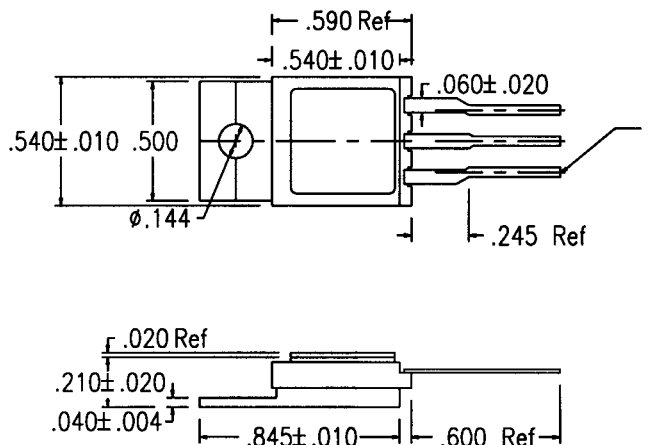
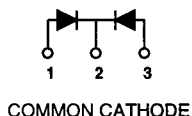
ELECTRICAL CHARACTERISTICS (Per Leg)

CHARACTERISTICS	SYMBOL	MAXIMUM	UNIT
Instantaneous Forward Voltage Drop ($I_F = 3 \text{ A}$ dc, $T_A = 25^\circ\text{C}$, 300 μs Pulse) ($I_F = 5 \text{ A}$ dc, $T_A = 25^\circ\text{C}$, 300 μs Pulse) ($I_F = 10 \text{ A}$ dc, $T_A = 25^\circ\text{C}$, 300 μs Pulse)	VF1	0.73 0.80 0.90	Vdc
Instantaneous Forward Voltage Drop ($I_F = 5 \text{ A}$ dc, $T_A = -55^\circ\text{C}$, 300 μs Pulse)	VF2	0.86	Vdc
Reverse Leakage Current (Rated V_R , $T_A = 25^\circ\text{C}$, 300 μs pulse minimum)	IR1	50	μA
Reverse Leakage Current (Rated V_R , $T_A = 100^\circ\text{C}$, 300 μs pulse minimum)	IR2	2	mA
Junction Capacitance ($V_R = 10 \text{ Vdc}$, $T_A = 25^\circ\text{C}$, $f = 1 \text{ MHz}$)	CJ	400	pf

CASE OUTLINE: CERAMIC TO-254

PIN OUT:

PIN 1: ANODE 1
PIN 2: CATHODE
PIN 3: ANODE 2



TYPICAL OPERATING CURVES ($T_A = 25^\circ\text{C}$ Unless otherwise specified)

